Docket No.: 50088-057

PATENT

IN THE UNITED STATES PATENT AND TRADEMARK OFFICE

In re Application of

DEC 2 0 2002

Masami SHIROSAKI, et al.

Serial No.: 09/833,734

Filed: April 13, 2001

Group Art Unit: 2823

Examiner: Julio J. Maldonado

SEMICONDUCTOR DEVICE AND METHOD FOR PRODUCING A For:

SEMICONDUCTOR DEVICE

AMENDMENT

Commissioner for Patents Washington, DC 20231

Sir:

01 FC:1201

The following Amendment and Remarks are submitted in response to the Office Action dated August 20, 2002.

IN THE SPECIFICATION:

Please amend the paragraph beginning at page 15, line 23 as follows:

As shown in Figure 3, the amorphous silicon film [13b] 13a remains without discontinuation in the inner wall of the cylindrical portion 6d, and surface of the 01/08/2003 JUILLIA1 00000001 500417 09833734 ambightous silicon film [13b] 13a is smooth. The remaining amorphous silicon film

> [13b] 13a is sufficient to keep the physical strength of the cylindrical portion 6b even after the formation of the silicon grains 13b.

Please amend the paragraph beginning at page 19, line 18 as follows: